

## 8th CIES Technology Forum VIRTUAL

March 27 (Mon) – 28 (Tue), 2023

## **International Symposium**

## Part 1 [Live] 9:00-12:10 (JST)

March DAY2 28 (Tue) DAY2

http://www.cies.tohoku.ac.jp/8th\_forum/

JST	PDT	CET				
9:00-9:05	March 27 17:00-17:05	1:00-1:05	Opening remarks	Tetsuo Endoh (Tohoku Univ.)		
9:05-9:35	17:05-17:35	1:05-1:35	Invited talk 1	Tae Young Lee (Samsung Electronics)		
			Status and Outlook of eMRAM Technology			
9:35-10:05	17:35-18:05	1:35-2:05	Invited talk 2	Chi-Feng Pai (TSMC)		
			Material Development toward Low Power SOT-MRAM			
10:05-10:35	18:05-18:35	2:05-2:35	Invited talk 3	Sooman Seo (SK Hynix)		
			First Demonstration of Full Integration and Characterization			
			of 4F <sup>2</sup> 1S1M Cells with 45 nm of Pitch and 20 nm of MTJ Size			
10:35-11:05	18:35-19:05	2:35-3:05	Invited talk 4	Hiroaki Honjo (Tohoku Univ.)		
			iPMA-type Hexa-MTJ for High Density eFlash-type MRAM			
11:05-11:35	19:05-19:35	3:05-3:35	Invited talk 5	Alex Lidow (Efficient Power Conversion)		
			GaN IC Roadmaps			
11:35-12:05	19:35-20:05	3:35-4:05	Invited talk 6	Yoshikazu Takahashi (Tohoku Univ.)		
			Progress in Power Electronics Integration Technology			
12:05-12:10	20:05-20:10	4:05-4:10	Closing remarks	Tetsuo Endoh (Tohoku Univ.)		
Part 2 [Streaming] 17:00-20:10 (JST)						
JST	PDT	CET				
17:00-17:05	1:00-1:05	9:00-9:05	Opening remarks	Tetsuo Endoh (Tohoku Univ.)		
17:05-17:35	1:05-1:35	9:05-9:35	Invited talk 1	Tae Young Lee (Samsung Electronics)		

17:05-17:35	1:05-1:35	9:05-9:35			
17.05-17.55	1.05-1.55	9.05-9.55	Status and Outlook of eMRAM Technology		
17.25 10.05	1:35-2:05	9:35-10:05	Invited talk 2	Chi-Feng Pai (TSMC)	
17:35-18:05			Material Development toward Low Power SOT-MRAM		
			Invited talk 3	Sooman Seo (SK Hynix)	
18:05-18:35	2:05-2:35	10:05-10:35	First Demonstration of Full Integration and Characterization		
			of 4F <sup>2</sup> 1S1M Cells with 45 nm of Pitch and 20 nm of MTJ Size		
18:35-19:05	2:35-3:05	10:35-11:05	Invited talk 4	Hiroaki Honjo (Tohoku Univ.)	
			iPMA-type Hexa-MTJ for High Density eFlash-type MRAM		
19:05-19:35	3:05-3:35	11:05-11:35	Invited talk 5	Alex Lidow (Efficient Power Conversion)	
			GaN IC Roadmaps		
10.25 20.05	3:35-4:05	11.35-12.05	Invited talk 6	Yoshikazu Takahashi (Tohoku Univ.)	
19:35-20:05			Progress in Power Electronics Integration Technology		
20:05-20:10	4:05-4:10	12:05-12:10	Closing remarks	Tetsuo Endoh (Tohoku Univ.)	

Organizer:Center for Innovative Integrated Electronic Systems (CIES), Tohoku Univ.Co-sponsored:Research Institute of Electrical Communication (RIEC), Tohoku Univ.Sponsors:CAO, MEXT, METI, JPO, JSPS, JST, NEDO, INPIT